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## BD233/235/237

# Medium Power Linear and Switching Applications

• Complement to BD 234/236/238 respectively



# **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

| Symbol           | Para  | meter   | Value      | Units |
|------------------|---|---------|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                      | : BD233 | 45         | V     |
|                  |   | : BD235 | 60         | V     |
|                  |   | : BD237 | 100        | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                   | : BD233 | 45         | V     |
|                  |   | : BD235 | 60         | V     |
|                  |   | : BD237 | 80         | V     |
| V <sub>CER</sub> | Collector-Emitter Voltage                   | : BD233 | 45         | V     |
|                  |   | : BD235 | 60         | V     |
|                  |   | : BD237 | 100        | V     |
| $V_{EBO}$        | Emitter-Base Voltage                        |         | 5          | V     |
| I <sub>C</sub>   | Collector Current (DC)                      |         | 2          | Α     |
| I <sub>CP</sub>  | *Collector Current (Pulse)                  |         | 6          | Α     |
| P <sub>C</sub>   | Collector Dissipation (T <sub>C</sub> =25°C | :)      | 25         | W     |
| T <sub>J</sub>   | Junction Temperature                        |         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                         |         | - 65 ~ 150 | °C    |

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

| Symbol                 | Parameter                              | Test Condition                       | Min. | Тур. | Max. | Units |
|------------------------|--|--------------------------------------|------|------|------|-------|
| V <sub>CEO</sub> (sus) | * Collector-Emitter Sustaining Voltage |                                      |      |      |      |       |
|                        | : BD233                                | $I_{C} = 100 \text{mA}, I_{B} = 0$   | 45   |      |      | V     |
|                        | : BD235                                | _                                    | 60   |      |      | V     |
|                        | : BD237                                |                                      | 80   |      |      | V     |
| I <sub>CBO</sub>       | Collector Cut-off Current              |                                      |      |      |      |       |
|                        | : BD233                                | $V_{CB} = 45V, I_{E} = 0$            |      |      | 100  | μΑ    |
|                        | : BD235                                | $V_{CB} = 60V, I_{E} = 0$            |      |      | 100  | μΑ    |
|                        | : BD237                                | $V_{CB} = 100V, I_{E} = 0$           |      |      | 100  | μΑ    |
| I <sub>EBO</sub>       | Emitter Cut-off Current                | $V_{EB} = 5V, I_{C} = 0$             |      |      | 1    | mA    |
| h <sub>FE</sub>        | * DC Current Gain                      | $V_{CE} = 2V, I_{C} = 150 \text{mA}$ | 40   |      |      |       |
|                        |  | $V_{CE} = 2V, I_{C} = 1A$            | 25   |      |      |       |
| V <sub>CE</sub> (sat)  | * Collector-Emitter Saturation Voltage | $I_C = 1A, I_B = 0.1A$               |      |      | 0.6  | V     |
| V <sub>BE</sub> (on)   | * Base-Emitter ON Voltage              | $V_{CE} = 2V$ , $I_{C} = 1A$         |      |      | 1.3  | V     |
| f <sub>T</sub>         | Current Gain Bandwidth Product         | $V_{CE} = 10V, I_{C} = 250mA$        | 3    |      |      | MHz   |

<sup>\*</sup> Pulse Test: PW=300µs, duty Cycle=1.5% Pulsed

# **Typical Characteristics**

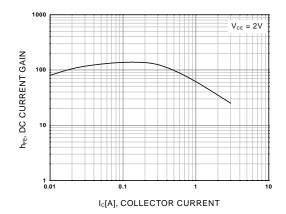


Figure 1. DC current Gain

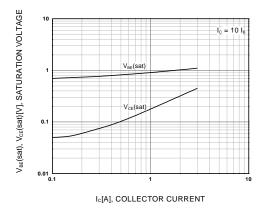


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

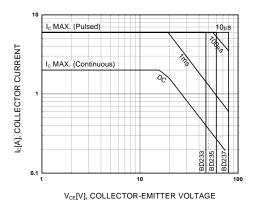


Figure 3. Safe Operating Area

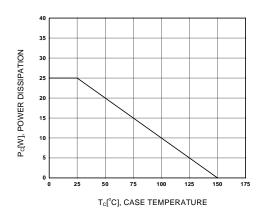
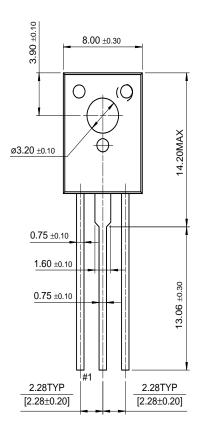
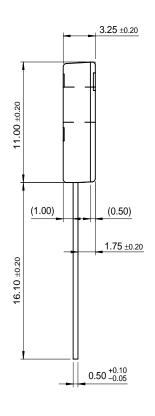


Figure 4. Power Derating

# **Package Demensions**

TO-126







Dimensions in Millimeters

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